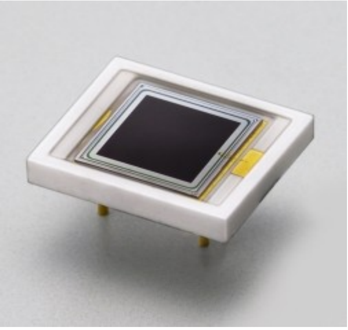
- The first tests showed that for the counter, based on the 6 x 6 x 30 cm^3 CsI(pure) crystal (AMCRYS) and 1 APD Hamamatsu S8664-1010 (1 cm^2, C_{APD} = 270 pF) coupled to the back facet of the crystal with optical grease (OKEN-6262A) has the light output LO = 26 ph.el./cm^2/MeV (for the shaping time of 30 ns), which corresponds to ENE ≈ 2 MeV. Such a small LO and large ENE substantially degrade the energy resolution of the calorimeter (σ_E/E (100 MeV) ≈ 8%). The acceptable parameters are:
LO ≥ 150 ph.el./MeV, ENE < 0.4 MeV → σ_E/E (100 MeV) = 3.7% (3.4% from the fluctuations of the shower leakage)

- The reason of the small LO: small sensitive area of APD (1/36 of the area of the crystal facet), small quantum efficiency ((20 – 30)%) for the UV scintillation light (320 nm). The reason of large ENE = ENC/LO: small LO and large ENC (large capacitance of Hamamatsu S8664-1010, small shaping time τ = 30 ns → thermal noise ~$C_{APD}/(\sqrt{\tau} * g_{FET})$ dominates).

- The ways to improve LO and ENE:
  - Increase the number of APDs (LO ~ N_{APD}, ENE ~ $1/\sqrt{N_{APD}}$) → too expensive
  - **Use smaller area APDs: 4 APDs S8664-55 (0.25 cm^2, C_{APD} = 85 pF) (LO is the same, ENE is smaller by a factor of $1/\sqrt{N_{APD}}$ = 0.5)**
  - **Apply wavelength shifter (WLS) (320 nm → 600 nm)**
  - **Optimize the input circuit of the preamplifier (increase g_{FET})**



We chose the configuration:
CsI(pure) + WLS (nanostructured organosilicon luminophores) + 4 APDs (Hamamatsu S8664-55)